



Description

The 74LVC1G04Q is an automotive-compliant, single inverter gate with a standard push-pull output. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

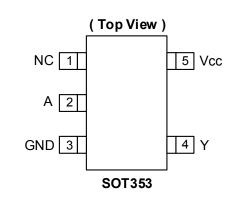
The gate performs the positive Boolean function:

 $Y = \overline{A}$

Features

- Grade 1 Ambient Temperature Operation: -40°C to 125°C
- Wide Supply Voltage Range from 1.65V to 5.5V
- ±24mA Output Drive at 3.3V
- CMOS Low Power Consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs Accept up to 5.5V Regardless of Vcc Level
- ESD Protection Tested per AEC-Q100
- Exceeds 2000V Human Body Model (AEC Q100-002)
- Exceeds 1000V Charged Device Model (AEC Q100-011)
- Latch-Up Exceeds 100mA (AEC Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74LVC1G04Q is suitable for automotive applications requiring specific change control and is AEC-Q100 qualified, has a grade 1 -40°C to 125°C temperature rating, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

Pin Assignments



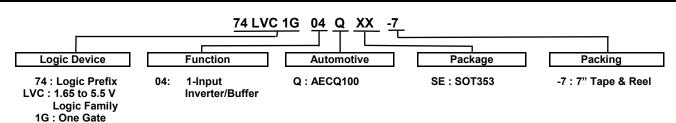
Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide Array of Products such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Ordering Information (Note 4)



Part Number	Package	Package	Package 7" Tape and Reel		nd Reel
Fait Nulliber	Code	(Notes 5 & 6)	Size	Quantity	Part Number Suffix
74LVC1G04QSE-7	SE	SOT353	2.0mm × 2.0mm × 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7

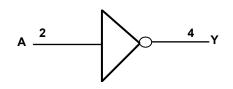
For packaging details, go to our website at http://www.diodes.com/products/packages.html.
Pad layout as shown in Diodes Inc. suggested pad layouts, which can be found on our website at see http://www.diodes.com/package-outlines.html.
The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf.

Pin Descriptions

Notes:

Pin Name	Description
NC	No Connection
А	Data Input
GND	Ground
Y	Data Output
V _{CC}	Supply Voltage

Logic Diagram



Function Table

Inputs	Output
Α	Y
Н	L
L	Н



Absolute Maximum Ratings (Notes 7 & 8)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or IOFF State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} +0.5	V
l _{IK}	Input Clamp Current VI<0	-50	mA
I _{ОК}	Output Clamp Current	-50	mA
lo	Continuous Output Current	±50	mA
ICC, IGND	Continuous Current Through V _{CC} or GND	±100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Notes: 7. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

8. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

Symbol		Parameter	Min	Max	Unit	
		Operating	1.65	5.5	V	
V _{CC}	Operating Voltage	Data Retention Only	1.5	—	V	
	V _{CC} = 1.65V to 1.95V	0.65 × V _{CC}	—			
N/		V _{CC} = 2.3V to 2.7V	1.7	—	V	
VIH	High-Level Input Voltage	V _{CC} = 3V to 3.6V	2	—	v	
		V _{CC} = 4.5V to 5.5V	0.7 × V _{CC}	—		
		V _{CC} = 1.65V to 1.95V	—	0.35 × V _{CC}		
V		V _{CC} = 2.3V to 2.7V	—	0.7	V	
VIL	Low-Level Input Voltage	V _{CC} = 3V to 3.6V	—	0.8	v	
		V _{CC} = 4.5V to 5.5V	—	0.3 × V _{CC}		
VI		Input Voltage	0	5.5	V	
Vo	(Dutput Voltage	0	V _{CC}	V	
	V _{CC} = 1.65V	—	-4			
		V _{CC} = 2.3V	—	-8	mA	
lau	High-Level Output Current	V _{CC} = 2.7V	—	-12		
Іон		V _{CC} = 3V	—	-16		
		VCC - 3V	_	-24		
		$V_{\rm CC}$ = 4.5V	—	-32		
		V _{CC} = 1.65V	—	4		
		$V_{CC} = 2.3V$	—	8		
I _{OL}	Low-Level Output Current	V _{CC} = 2.7V	—	12	mA	
IOL		$V_{\rm CC} = 3V$		16		
			—	24		
		V _{CC} = 4.5V	—	32		
	Input Transition Rise or Fall	V_{CC} = 1.8V ± 0.15V, 2.5V ± 0.2V		20		
Δt/ΔV Input Transition Rise or Fa Rate		$V_{CC} = 3.3V \pm 0.3V$		10	ns/V	
		$V_{CC} = 5V \pm 0.5V$		5		
T _A	Operating Free-Air Temperature	_	-40	+125	°C	

Recommended Operating Conditions (Note 9)

Note: 9. Unused inputs should be held at V_{CC} or Ground.



Electrical Characteristics (All typical values are at V_{CC} = 3.3V, T_A = +25°C)

Ourseland.	Devenator	Test C	a a diti a n a	N N	-40°	C to +125	°C	l lució			
Symbol	Parameter	Test Conditions		Vcc	Min	Тур	Max	Unit			
			I _{OH} = -100μA	1.65V to 5.5V	V _{CC} -0.1	—	—				
			I _{OH} = -4mA	1.65V	0.95	—	—				
N	Lligh Lovel Output Veltage	V - V	I _{OH} = -8mA	2.3V	1.7	—	—	v			
V _{OH}	High Level Output Voltage	$V_I = V_{IL}$	I _{OH} = -12mA	2.7V	1.9	—	—	v			
			I _{OH} = -24mA	3V	2.0	—	—				
			I _{OH} = -32mA	4.5V	3.4	—	—				
						I _{OL} = 100μA	1.65V to 5.5V	_	—	0.10	
			I _{OL} = 4mA	1.65V	—	—	0.70	V			
. <i>.</i>			I _{OL} = 8mA	2.3V	_	—	0.45				
V _{OL}	Low Level Output Voltage	$V_{I} = V_{IH}$	$I_{OL} = 12mA$	2.7V	_	_	0.60				
			I _{OL} = 24mA	3V	_	—	0.80				
			I _{OL} = 32mA	4.5V	_	_	0.80				
lı –	Input Current	V _I = 5.5V or GN	ND	0 to 5.5V	_	±0.1	±1	μA			
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 5.5V$,	0V	—	—	±2	μA			
I _{CC}	Supply Current	V _I = 5.5V or GND I _O =0		5.5V	_	0.1	4	μA			
Δlcc	Additional Supply Current	Input at V _{CC} –	0.6V	3V to 5.5V	_	_	500	μA			
CI	Input Capacitance	$V_i = GND$ to V_C	c	3.3V	—	5.0	—	pF			

Package Characteristics

Symbol	Parameter	Test Conditions	V _{cc}	Min	Тур.	Max	Unit
θJA	Thermal Resistance Junction-to-Ambient	SOT353	Note 10	_	371	_	°C/W
θις	Thermal Resistance Junction-to-Case	SOT353	Note 10	_	143		°C/W

Note: 10. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

Figure 1 Typical Values at T_A = +25°C and nominal voltages 1.8V, 2.5V, 2.7V, 3.3V, and 5.0V.

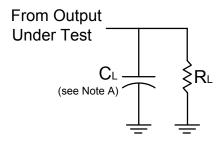
Parameter	From	То	Ma a	T _A = -40°C to 125°C			Unit
Farameter	Input	Output	V _{cc}	Min	Тур	Max	Unit
			1.8V ± 0.15V	1.0	3.0	9.5	
			2.5V ± 0.2V	0.5	2.0	6.5	
t _{PD}	А	Y	2.7V	0.5	2.3	7.0	ns
			3.3V ± 0.3V	0.5	2.0	5.5	
			5.0V ± 0.5V	0.5	1.6	5.0	

Operating Characteristics

T _A = +25°C							1
Parameter		Test	V _{CC} = 1.8V	$V_{CC} = 2.5V$	$V_{CC} = 3.3V$	$V_{CC} = 5V$	Unit
		Conditions	Тур	Тур	Тур	Тур	Unit
C _{pd}	Power Dissipation Capacitance	f = 10 MHz	15	16	16	16	pF



Measurement Information



Vcc	Inputs		V _M	CL	RL
VCC	VI	t _r /t _f	¥ M	5	κ <u>ι</u>
1.8V ± 0.15V	V _{CC}	≤2ns	V _{CC} /2	30pF	1ΚΩ
2.5V ± 0.2V	V _{CC}	≤2ns	V _{CC} /2	30pF	500Ω
2.7V	V _{CC}	≤2.5ns	1.5V	50pF	500Ω
3.3V ± 0.3V	3.0V	≤2.5ns	1.5V	50pF	500Ω
5.0V ± 0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50pF	500Ω



Voltage Waveform Pulse Duration

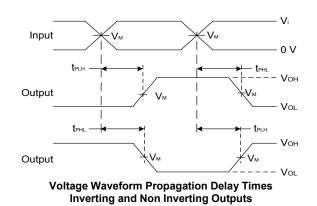


Figure 1 Load Circuit and Voltage Waveforms

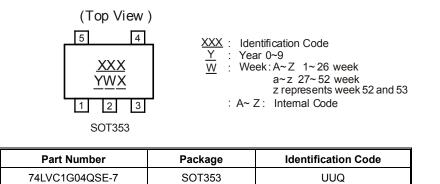
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{\text{PD}}.$



Marking Information

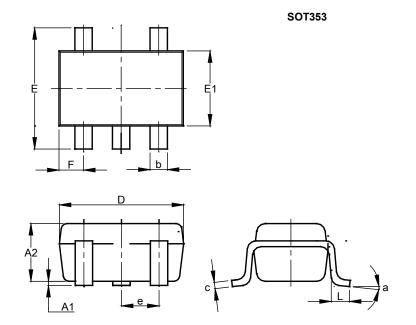
SOT353





Package Outline Dimensions

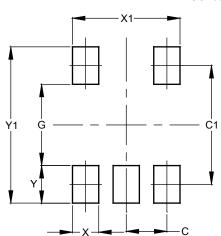
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SC	T353	
Dim	Min	Max	Тур
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
С	0.10	0.22	0.11
D	1.80	2.20	2.15
Е	2.00	2.20	2.10
E1	1.15	1.35	1.30
е	0).650 B	SC
F	0.40	0.45	0.425
L	0.25	0.40	0.30
а	0°	8°	
All	Dimen	sions	in mm

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
C1	1.900
G	1.300
Х	0.420
X1	1.720
Y	0.600
Y1	2.500

SOT353



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